

A Low-Loss Bandpass Filter Using Electrically Coupled High- Q $TM_{01\delta}$ Dielectric Rod Resonators

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Abstract—For a $TM_{01\delta}$ mode dielectric rod resonator placed coaxially in a TM_{01} cutoff circular waveguide, the resonant characteristics such as the resonant frequency, its temperature coefficient, the unloaded Q , and the other resonances, are discussed on the basis of results calculated accurately by the mode-matching method. The results show that this resonator compares favorably to a conventional $TE_{01\delta}$ mode dielectric resonator, particularly for realization of a high unloaded Q . Analytical results also verify that interresonator coupling between these two resonators can be expressed equivalently by a capacitively coupled LC resonant circuit. A four-stage Chebyshev filter having a ripple of 0.035 dB and an equiripple bandwidth of 27 MHz at a center frequency of 11.958 GHz is fabricated using these resonators. Low loss and good spurious characteristics are realized for this filter; i.e., the insertion loss is 0.5 dB, which corresponds to an unloaded Q of 17000, and no spurious response appears in the frequency range below 17 GHz.

I. INTRODUCTION

BANDPASS filters constructed by placing $TE_{01\delta}$ mode dielectric resonators coaxially in a TE_{01} mode cutoff circular cylindrical waveguide were first presented by Harrison [1] and Cohn [2]. The precise design of such filters was performed on the basis of a rigorous analysis by the mode-matching method [3], [4]. For filters using the $TM_{01\delta}$ mode of dielectric resonators, on the other hand, few investigations have been presented [5], [6].

In this paper a design and characteristics are discussed for a Chebyshev bandpass filter constructed by placing $TM_{01\delta}$ mode dielectric rod resonators coaxially in a TM_{01} mode cutoff circular waveguide. A rigorous analysis of interresonator coupling and a precise design of high- Q $TM_{01\delta}$ resonators are performed by the mode-matching technique in a way similar to that of the $TE_{01\delta}$ case [3], [4], [7]. Some discussions verify that the interresonator coupling for this case is equivalently expressed by a capacitively coupled LC resonant circuit. This is in contrast to the inductively coupled case for the $TE_{01\delta}$ mode [3], [4], [7]. A four-stage Chebyshev filter having a ripple of 0.035 dB and an equiripple bandwidth of 27 MHz at a center frequency of 11.958 GHz is fabricated using these res-

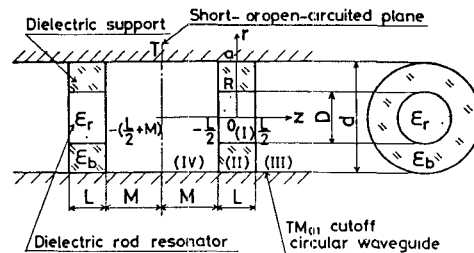


Fig. 1. Coupled dielectric rod resonators.

onators. Experiment shows low loss and good spurious characteristics of this filter.

II. ANALYSIS

A. Interresonator Coupling Coefficient

Fig. 1 shows the geometry of the coupled dielectric rod resonators to be analyzed and the cylindrical coordinate system r, θ, z . Two dielectric rod resonators having relative permittivity ϵ_r , diameter D , and length L are each supported coaxially in a cutoff circular waveguide of diameter d with dielectric rings of relative permittivity ϵ_b . The space between the rods is $2M$. The relative permeability in each medium is $\mu_r = 1$. The conductor and dielectric are assumed to be lossless at first.

As discussed below, the interresonator coupling coefficient of the coupled $TM_{01\delta}$ dielectric resonators k is given by

$$k = \frac{f_{op}^2 - f_{sh}^2}{f_{op}^2 + f_{sh}^2} \quad (1)$$

where f_{op} and f_{sh} are the resonant frequencies when the structurally symmetric plane T shown in Fig. 1 is open- and short-circuited, respectively. An analysis for these resonant frequencies can be performed rigorously by the mode-matching technique in a way similar to that of the $TE_{01\delta}$ case [3], [4], [7]. We shall describe it below. According to the structural symmetry, we consider only the region $z \geq -(L/2 + M)$, which is divided into four homogeneous media I to IV. Quantities in the four media are designated by subscripts 1 to 4, respectively. An axial component of the electric Hertz vector π_e in each medium is expanded in eigenmodes which satisfy the boundary conditions on the

Manuscript received April 15, 1988; revised August 9, 1988.

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IEEE Log Number 8824200.

conductor surface and on the T plane, i.e.,

$$\begin{aligned}\pi_{e1} &= \sum_{p=1}^{\infty} A_p J_0(k_{1p}r) \cos(\beta_p z - \phi_p) \\ \pi_{e2} &= \sum_{p=1}^{\infty} B_p \left[I_0(k'_{2p}r) - \frac{I_0(k'_{2p}a)}{K_0(k'_{2p}a)} K_0(k'_{2p}r) \right] \\ &\quad \cdot \cos(\beta_p z - \phi_p) \\ \pi_{e3} &= \sum_{q=1}^{\infty} C_q J_0(k_q r) \exp(-\alpha_q z) \\ \pi_{e4} &= \sum_{q=1}^{\infty} D_q J_0(k_q r) \left\{ \begin{array}{l} \sinh \alpha_q (z + L/2 + M) \\ \cosh \alpha_q (z + L/2 + M) \end{array} \right\} \quad (2)\end{aligned}$$

where

$$\begin{aligned}\beta_p^2 &= k_0^2 \epsilon_r - k_{1p}^2 = k_0^2 \epsilon_b + k'_{2p}{}^2 \\ \alpha_q^2 &= k_q^2 - k_0^2 = (j_{0q}/a)^2 - k_0^2 \\ J_0(j_{0q}) &= 0 \quad k_0 = 2\pi f_0/c. \quad (3)\end{aligned}$$

Also, the upper and lower expressions in the braces $\{ \}$ correspond to the open- and short-circuited T plane cases, respectively. $J_n(x)$ is the Bessel function of the first kind, $I_n(x)$ and $K_n(x)$ are the modified Bessel functions of the first and second kinds, f_0 is the resonant frequency, and c is the light velocity in vacuum. Expansion coefficients A_p , B_p , ϕ_p , C_q , and D_q can be determined from boundary conditions. In the circular waveguide, the TM_{01} mode is assumed to be the evanescent mode, i.e.,

$$d < \frac{c}{\pi f_0} j_{01}, \quad j_{01} = 2.405 \quad (4)$$

so that α_q is real for any q .

The field components in each medium are given by substituting (2) into the following Maxwell's equations:

$$E_z = k_0^2 \epsilon_i \pi_{ei} + \frac{\partial^2 \pi_{ei}}{\partial z^2} \quad E_r = \frac{\partial^2 \pi_{ei}}{\partial r \partial z} \quad H_\theta = -j\omega \epsilon_0 \epsilon_i \frac{\partial \pi_{ei}}{\partial r} \quad (5)$$

where $i=1, 2, 3, 4$, and $\epsilon_0 \epsilon_i$ is the permittivity of the i th medium.

In media I and II, at first, the requirement that the p th components of E_z and H_θ be continuous at the interface $r=R$ leads to

$$\begin{aligned}\frac{u_p J_0(u_p)}{\epsilon_r J_1(u_p)} &= \frac{v'_p}{\epsilon_b} \left[I_0(v'_p) - \frac{I_0(v'_p S)}{K_0(v'_p S)} K_0(v'_p) \right] \\ &\quad \left/ \left[I_1(v'_p) + \frac{I_0(v'_p S)}{K_0(v'_p S)} K_1(v'_p) \right] \right. \quad (6)\end{aligned}$$

where

$$u_p = k_{1p} R \quad v'_p = k'_{2p} R = R \sqrt{k_0^2 (\epsilon_r - \epsilon_b) - (u_p/R)^2}. \quad (7)$$

In the above, a set of u_p and v'_p is the p th solution for (6), where $u_p < u_{p+1}$ ($p=1, 2, \dots$). Then, imposing the boundary conditions that E_r and H_θ be continuous at $z=L/2$ and $z=-L/2$, and applying the orthogonality of the Bessel functions, we obtain homogeneous equations for the expansion coefficients. The resonant frequencies are determined by the requirement that the determinant of the coefficient matrix vanish, i.e.,

$$\det H(f_0; \epsilon_r, \epsilon_b, d, D, L, M) = 0 \quad (8)$$

where elements of the $N \times N$ square matrix ($p, q=1, 2, \dots, N/2$) are given by

$$\begin{aligned}H_{2p-1, 2q-1} &= T_{pq} \frac{\beta_p}{\alpha_q} \tan \frac{\beta_p L}{2} - \epsilon_r R_{pq} \\ H_{2p-1, 2q} &= - \left(\frac{T_{pq}}{\alpha_q L} + \frac{\epsilon_r R_{pq}}{\beta_p L} \tan \frac{\beta_p L}{2} \right) \\ H_{2p, 2q-1} &= T_{pq} \frac{\beta_p}{\alpha_q} \left\{ \frac{\tanh \alpha_q M}{\coth \alpha_q M} \right\} \tan \frac{\beta_p L}{2} - \epsilon_r R_{pq} \\ H_{2p, 2q} &= \frac{T_{pq}}{\alpha_q L} \left\{ \frac{\tanh \alpha_q M}{\coth \alpha_q M} \right\} + \frac{\epsilon_r R_{pq}}{\beta_p L} \tan \frac{\beta_p L}{2} \quad (9)\end{aligned}$$

and also

$$\begin{aligned}T_{pq} &= P_{pq} - \frac{B_p v'_p}{A_p u_p} Q_{pq} \quad R_{pq} = P_{pq} - \frac{\epsilon_b B_p v'_p}{\epsilon_r A_p u_p} Q_{pq} \\ P_{pq} &= \frac{1}{a^2} \int_0^R r J_1(k_{1p}r) J_1(k_q r) dr \\ Q_{pq} &= \frac{1}{a^2} \int_R^a r \left[I_1(k'_{2p}r) + \frac{I_0(k'_{2p}a)}{K_0(k'_{2p}a)} K_1(k'_{2p}r) \right] J_1(k_q r) dr \\ \frac{B_p}{A_p} &= - \frac{u_p^2}{v_p'^2} J_0(u_p) / \left[I_0(v'_p) - \frac{I_0(v'_p S)}{K_0(v'_p S)} K_0(v'_p) \right]. \quad (10)\end{aligned}$$

In practical calculations, N is chosen to be a value for which the solution converges to the desired accuracy.

B. Resonant Frequency, Unloaded Q , and Temperature Coefficient for Single Resonator

Putting $M=\infty$ in (8), we can calculate resonant frequencies for a single resonator. In this case, elements of the $N \times N$ square matrix ($p, q=1, 2, \dots, N$) are given by

$$H_{p,q} = T_{pq} \frac{\beta_p}{\alpha_q} \tan \frac{\beta_p L}{2} - \epsilon_r R_{pq}. \quad (11)$$

The unloaded Q (Q_u) of the $\text{TM}_{01\delta}$ mode is given by

$$\frac{1}{Q_u} = \frac{1}{Q_d} + \frac{1}{Q_{db}} + \frac{1}{Q_c} \quad (12)$$

where Q_d , Q_{db} , and Q_c are Q factors due to the dielectric rod loss, the dielectric support loss, and the conductor loss, respectively. We can calculate Q_d and Q_{db} from (8) and (11) by the frequency perturbation technique [8]. But this technique is not applicable to the Q_c calculation for the

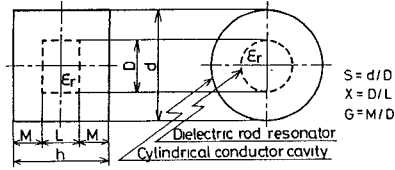


Fig. 2. Dielectric rod resonator in cavity.

TM mode. Then, we estimate the Q_c values from the calculation of stored energy and conductor loss for the structure shown in Fig. 2, using the relation $Q_c = (1/Q_{cy} + 1/Q_{ce})^{-1}$, where Q_{cy} and Q_{ce} are due to conductor losses of a cylinder and two end plates, respectively [9].

A formula for the temperature coefficient of the resonant frequency τ_f is expressed as follows:

$$\tau_f = A_r \tau_r + A_b \tau_b + A_\alpha \tau_\alpha + A_c \tau_c \quad (13)$$

where τ_r and τ_b are the temperature coefficients of ϵ_r and ϵ_b , and τ_α and τ_c are the coefficients of thermal linear expansion of the dielectric and conductor, respectively. Also, the constants A_r , A_b , A_α , and A_c can be calculated from (8) and (11) in a way similar to that of the TE_{018} case [4].

III. DESIGN OF TM_{018} DIELECTRIC ROD RESONATOR

The TM_{018} resonators used in this filter structure were fabricated from low-loss ceramics $Ba(ZnMgSbTa)O_3$ ($\epsilon_r = 24$, $\tan \delta = 4 \times 10^{-5}$ at 12 GHz, Ube Industries, Ltd.), polystyrene foam supports ($\epsilon_b = 1.031$, $\tan \delta = 4 \times 10^{-5}$), and copper-plated brass (conductivity $\sigma = \bar{\sigma} \sigma_0$; $\bar{\sigma} = 0.9$, $\sigma_0 = 58 \times 10^6$ S/m). High- Q design of these resonators was performed as described below.

Define a resonant frequency ratio F_r by $F_r = f_r/f_0$, where f_0 is the frequency of a particular mode of interest and f_r is that of the neighboring mode. In the case of $\epsilon_r = 24$, for the TE_{018} ring resonator we have already carried out a design for obtaining the highest Q_u value by keeping the value $F_r = 1.14$, which is the maximum value realized for the TE_{018} rod resonator [4]. A similar design was performed for the TM_{018} rod resonator. This result is shown in Fig. 3 together with mode charts. In this case the TM_{018} mode is the fourth highest mode and the optimum dimension ratios are $S^0 = d/D = 1.5$ and $X^0 = D/L = 1.8$. It is found also from Fig. 3 that $Q_d \tan \delta$ depends more strongly on S than on X and that the effect of Q_{db} on Q_u is quite small in comparison with the effects of Q_d and Q_c . Appropriate values of S and X realize the maximum value of $Q_c \delta_s / \lambda_0$, where $\delta_s = (\pi f_0 \mu \bar{\sigma} \sigma_0)^{-1/2}$ is the skin depth of the conductor and σ_0 is the conductivity of the international standard annealed copper. Comparison of Q_c with Q_{cy} curves shows that the ratio $G = M/D = 2.0$ is large enough to ignore the end plate loss.

Table I shows a comparison of both resonators for the Q_u values calculated when $f_0 = 11.958$ GHz; the Q_u value of the TM_{018} rod resonator is higher than that of the TE_{018} ring resonator. This stems from the fact that the Q_d value of the TM_{018} resonator is higher than that of the TE_{018}

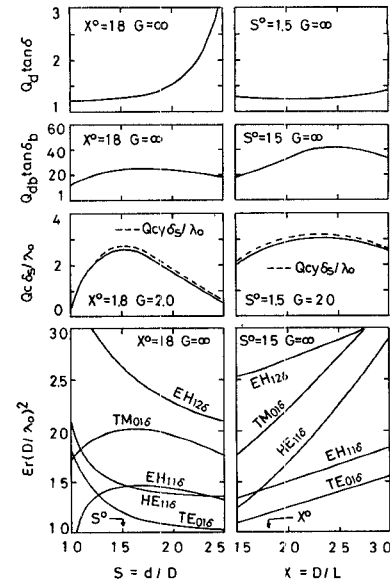


Fig. 3. Mode charts and normalized Q value of TM_{018} mode for a dielectric rod resonator in the case of $\epsilon_r = 24$, $\epsilon_b = 1.031$

TABLE I
CALCULATED Q_u VALUES OF THE TM_{018} ROD AND TE_{018} RING RESONATORS WITH $F_r = 1.14$ WHEN $f_0 = 11.958$ GHz, $\epsilon_r = 24$, $\tan \delta = 4 \times 10^{-5}$, $\epsilon_b = 1.031$, $\tan \delta_b = 4 \times 10^{-5}$, AND $\bar{\sigma} = 0.9$

Mode	Q_d	Q_{db}	Q_c	Q_u
TM_{018} Rod *1	31,000	610,000	100,000	23,000
TE_{018} Ring *2	26,000	1,000,000	97,000	20,000

*1 $D = 7.27$ mm, $D_x = 0$ mm, $L = 4.04$ mm, $d = 10.90$ mm

*2 $D = 4.94$ mm, $D_x = 1.48$ mm, $L = 3.63$ mm, $d = 11.80$ mm

resonator because of the smaller amount of electric field energy stored inside the dielectric, although the Q_c values are almost equal for the two resonators. The measured results were $Q_u = 21000$ for the TM_{018} resonator and $Q_u = 18000$ for the TE_{018} resonator; they are higher than $Q_u = 12000$ to 16000 for a TE_{113} cylindrical cavity resonator [10].

In addition, the τ_f value for this TM_{018} resonator is calculated from (13) and is given by

$$\tau_f = -0.405 \tau_r - 0.0205 \tau_b - 0.999 \tau_\alpha - 0.0101 \tau_c \quad (14)$$

Substituting $\tau_r = -18 \pm 0.5$ ppm/°C, $\tau_b = -8.4 \pm 0.5$ ppm/°C, $\tau_\alpha = 7.5 \pm 0.4$ ppm/°C, and $\tau_c = 20 \pm 0.03$ ppm/°C into (14), we obtain $\tau_f = -0.2 \pm 0.4$ ppm/°C, which agrees with the measured result $\tau_f = 0.3 \pm 0.3$ ppm/°C. Thus the temperature characteristic is excellent. It is also noted that the τ_c effect on τ_f is only -0.2 ppm/°C, which is less than -1.9 ppm/°C for the TE_{018} ring resonator [4].

IV. INTERRESONATOR COUPLING COEFFICIENT

For the coupled TM_{018} resonators, the calculated and measured results of f_{op} , f_{sh} , and k are shown in Fig. 4. These measured values agree with the theoretical curves to within 0.4, 0.4, and 2 percent, respectively. The calculated result shows $f_{op} > f_{sh}$, which is in contrast with the usual inductively coupled case for the TE_{018} mode in which

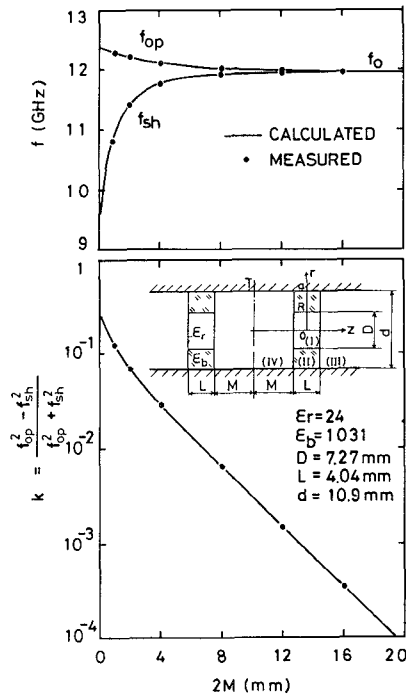


Fig. 4. Calculated and measured results of f_{op} , f_{sh} , and k versus $2M$ for coupled TM_{018} rod resonators.

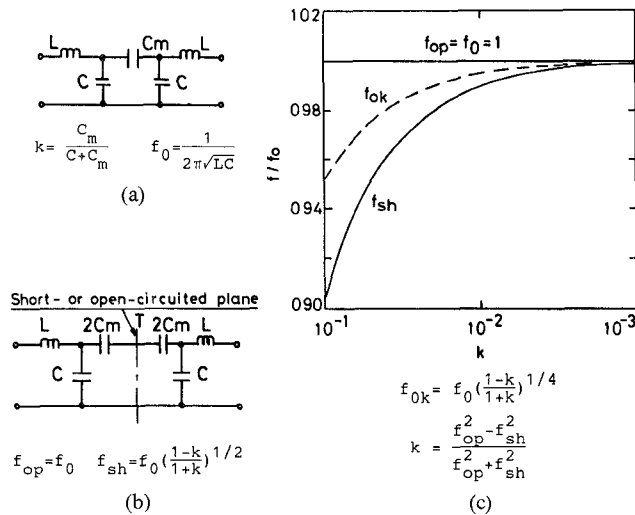


Fig. 5. Capacitively coupled LC resonant circuit.

$f_{sh} > f_{op}$ [3], [4], [7]. This fact is not overlooked in the paper presented by Zaki and Chen [7]. Cohn [2] has shown that the interresonator coupling is caused by an axial magnetic dipole for the TE_{018} mode. By analogy with this case, we can expect that it is done by an axial electric dipole for the TM_{018} mode. Then, we shall consider the capacitively coupled LC resonant circuit shown in Fig. 5(a). Fig. 5(b) shows this equivalent circuit, where f_{op} and f_{sh} are the resonant frequencies when the symmetric plane T is open- and short-circuited, respectively. Fig. 5(c) shows the result calculated using the equivalent circuit in Fig. 5(b). It is seen from Fig. 5(c) that $f_{op} > f_{sh}$, which is in accordance with the case of the coupled TM_{018} resonators. But this circuit is still incomplete because $f_{op} > f_0$ for the

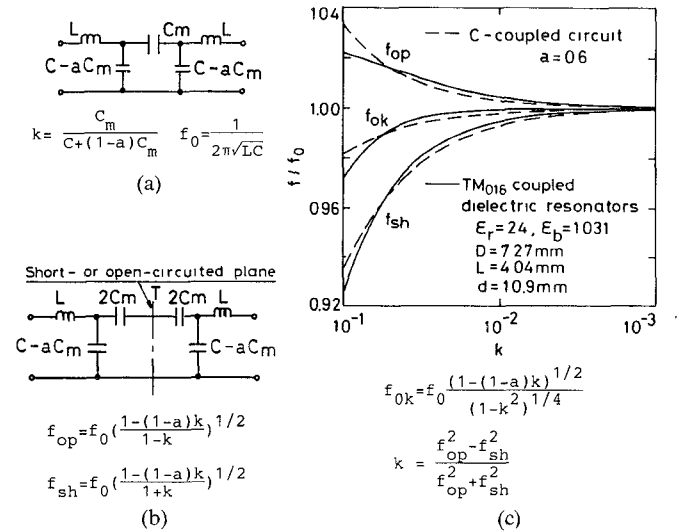


Fig. 6. Modified C -coupled LC resonant circuit.

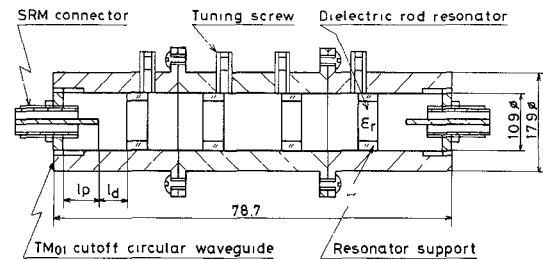


Fig. 7. Cross-sectional view of a four-stage dielectric rod resonator filter.

coupled resonators. In order to improve this, we modify this circuit into the one shown in Fig. 6(a). This equivalent circuit is shown in Fig. 6(b), where a compensation factor a is determined to make the f_{op} and f_{sh} values of the equivalent circuit fit with the ones for the coupled dielectric TM_{018} resonators. Fig. 6(c) shows the calculated results for $a = 0.6$, which is more suitable than Fig. 5(c). As a result, two dielectric resonators placed in a cutoff waveguide couple electrically with each other when the dominant evanescent waveguide mode is the TM mode, while they couple magnetically when the dominant evanescent mode is the TE mode.

The difference between the center frequency $f_{0k} = \sqrt{f_{op} \cdot f_{sh}}$ and f_0 is within 0.02 percent when $k < 6 \times 10^{-3}$; thus we can neglect it in the present narrow-bandwidth filter design. We should consider the change of f_{0k} for wide bandwidth filter design.

V. FILTER DESIGN

Fig. 7 shows the structure of a four-stage bandpass filter fabricated. Three brass rings are precisely machined with the designed dimensions and are copper plated. This structure eliminates the need for k -adjustment screws, because the $2M$ values can be determined precisely from the calculation. The resonant frequencies of the four resonators are each adjusted with tuning dielectric screws. The first and fourth resonators are each excited by

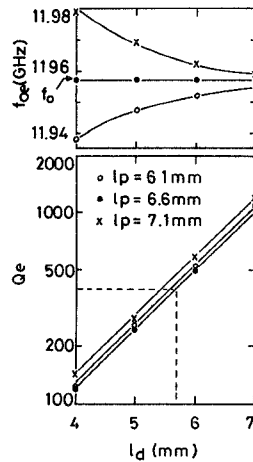


Fig. 8. Measured result for the resonator excited by monopole antenna in Fig. 7.

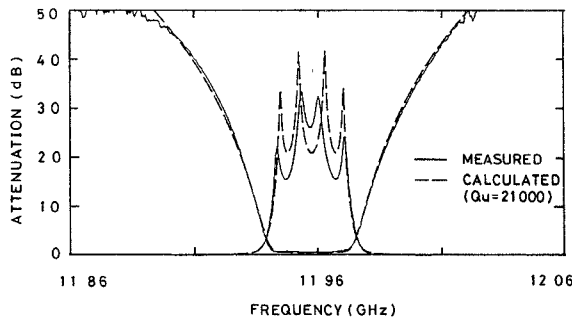


Fig. 9. Transmission and reflection responses of the four-stage Chebyshev bandpass filter.

monopole antennas. Fig. 8 shows the measured results for the resonant frequency f_{0e} and the external $Q(Q_e)$ versus the spacing between the monopole and the resonator l_d for the three cases of the monopole length l_p . The case $l_p = 6.6$ mm is the most suitable for the filter design, because we can adjust Q_e value as the resonant frequency is invariant at $f_{0e} = f_0$.

The Chebyshev filter specifications designed on the basis of application to a Japanese broadcasting satellite [10] are as follows: a center frequency of 11.958 GHz (ch. 13), a 15 dB bandwidth of 50 MHz, an equiripple bandwidth of 27 MHz, and a ripple of 0.035 dB. Thus we obtain the design values $k_{12} = k_{34} = 2.1 \times 10^{-3}$, $k_{23} = 1.6 \times 10^{-3}$, and $Q_e = 390$ from [11].

The transmission and reflection responses are shown in Fig. 9. In spite of the structure without k -adjustment screws, fairly good agreement between experiment and theory is obtained. Using the well-known formula in [12], we obtain an insertion loss of 0.4 dB for the measured value $Q_u = 21000$, while the measured insertion loss of 0.5 dB corresponds to $Q_u \approx 17000$. This Q_u degradation is due to the conductor loss of the coupling structure. This insertion loss is lower by 0.4 dB than that for the TE_{018} resonator filter [4]. The measured wide-band response is shown in Fig. 10. The resonant modes for the single resonator calculated are indicated on the top of the figure. The good spurious response was obtained because the

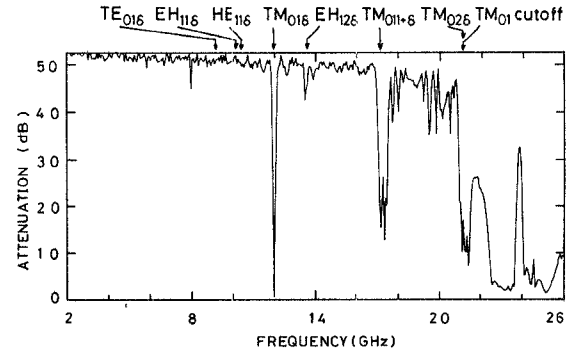


Fig. 10. Wide-band response of the filter.

excitation of the resonant modes other than the TM_{01} modes was suppressed by using the present monopole antennas. This spurious characteristic is superior to those for TE_{018} dielectric resonator filters [1], [3], [4] and for the TE_{113} cylindrical cavity resonator filter [10].

VI. CONCLUSIONS

For a TM_{018} mode dielectric rod resonator placed coaxially in a TM_{01} cutoff circular waveguide, the resonant characteristics such as the resonant frequency, its temperature coefficient, the unloaded Q , and the other resonances, were discussed on the basis of results calculated accurately by the mode-matching method. The result shows that this resonator compares favorably to a conventional TE_{018} mode dielectric resonator, particularly for realization of a high unloaded Q . In addition, it was shown that the interresonator coupling between these two resonators can be expressed equivalently by a capacitively coupled LC resonant circuit. As a result, a compact bandpass filter having low loss and good spurious characteristics are realized by using these TM_{018} resonators. The TM_{018} resonators will also be useful as filter constructions for waveguide circuits.

ACKNOWLEDGMENT

The authors would like to thank M. Katoh for his help with the filter fabrications.

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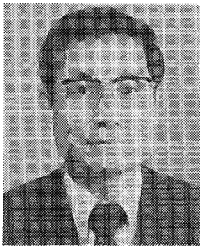
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